

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -100 | V |
| Collector-Emitter Voltage | V _{CEO} | -80 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -1 | A |
| Peak Pulse Collector Current | I _{CM} | -2 | |
| Continuous Base Current | I _B | -100 | mA |
| Peak Pulse Base Current | I _{BM} | -200 | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

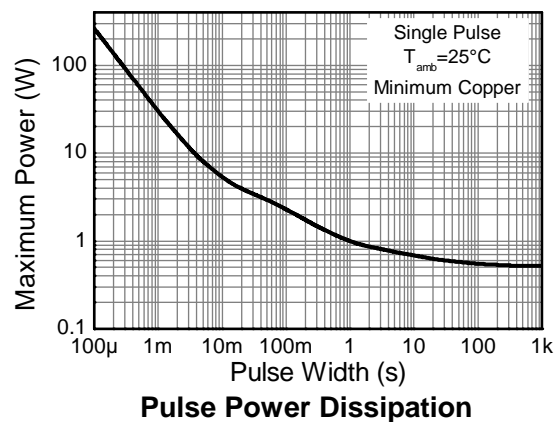
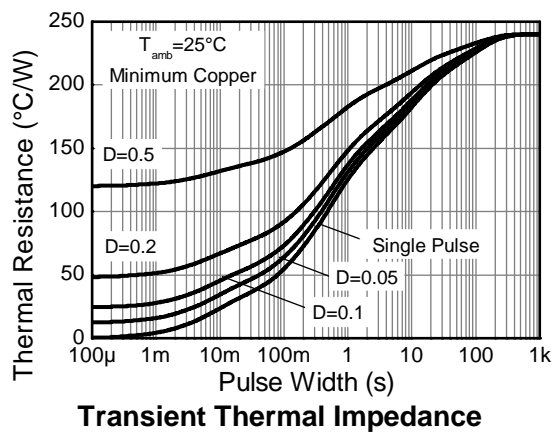
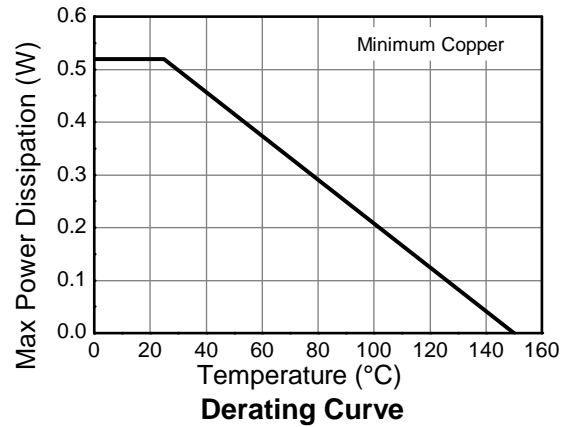
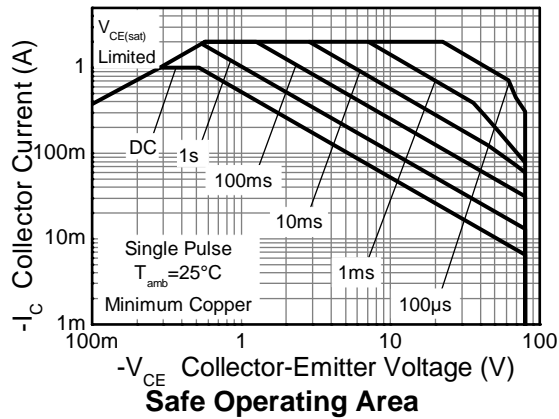
| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation | P _D | 520 | mW |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 240 | °C/W |
| Thermal Resistance, Junction to Leads | R _{θJL} | 20 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C |

ESD Ratings (Note 7)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- For a device mounted on minimum recommended pad layout FR4 PCB single sided 1oz copper; device is measured under still air conditions while operating in a steady-state.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|-----------------|-------------|---------------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -100 | - | - | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 8) | BV _{CEO} | -80 | - | - | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | - | - | V | I _E = -100μA |
| Collector Cut-off Current | I _{CBO} | - | - | -0.1 -20 | μA | V _{CB} = -30V V _{CB} = -30V, T _A = +150°C |
| Emitter Cut-off Current | I _{EBO} | - | - | -20 | nA | V _{EB} = -4V |
| Static Forward Current Transfer Ratio (Note 8) | h _{FE} | 25 100 25 | - - - | - 250 - | - | I _C = -5mA, V _{CE} = -2V I _C = -150mA, V _{CE} = -2V I _C = -500mA, V _{CE} = -2V |
| Collector-Emitter Saturation Voltage (Note 8) | V _{CE(sat)} | - | - | -0.5 | V | I _C = -500mA, I _B = -50mA |
| Base-Emitter Turn-On Voltage (Note 8) | V _{BE(on)} | - | - | -1.0 | V | I _C = -500mA, V _{CE} = -2V |
| Transition Frequency | f _T | - | 125 | - | MHz | I _C = -50mA, V _{CE} = -10V f = 100MHz |
| Output Capacitance | C _{obo} | - | - | 25 | pF | V _{CB} = -10V, f = 1MHz |

Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

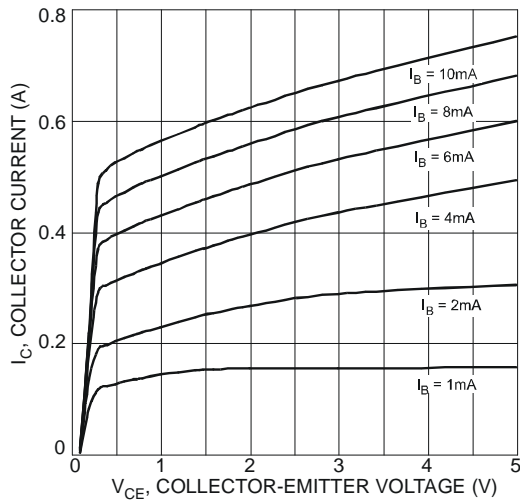


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

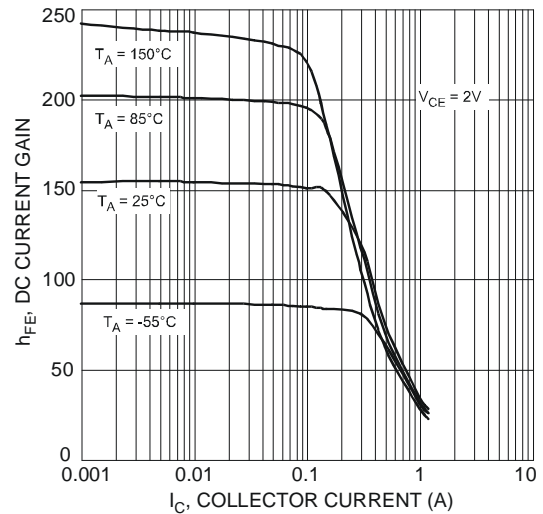


Fig. 2 Typical DC Current Gain vs. Collector Current

Typical Electrical Characteristics (continued)

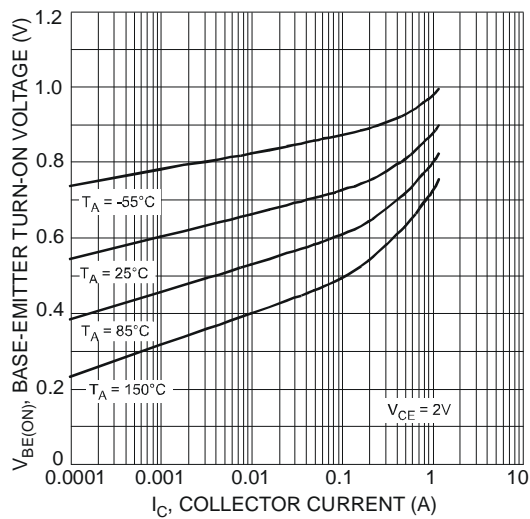


Fig. 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

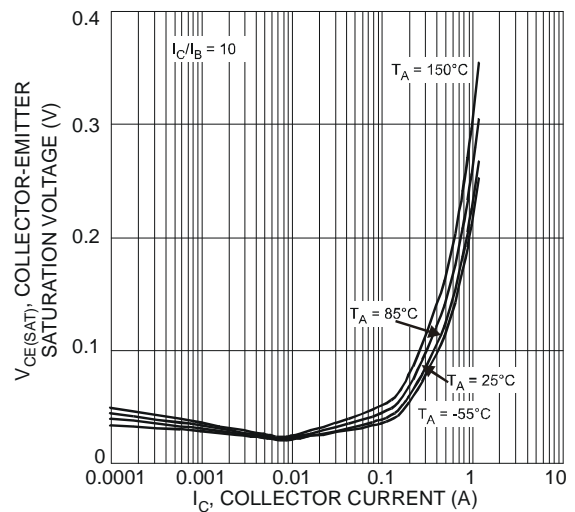


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

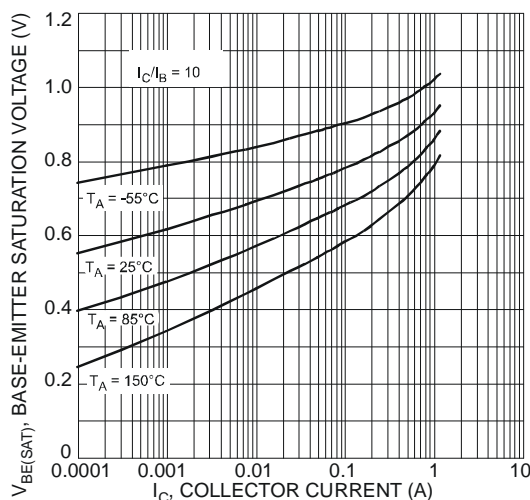


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

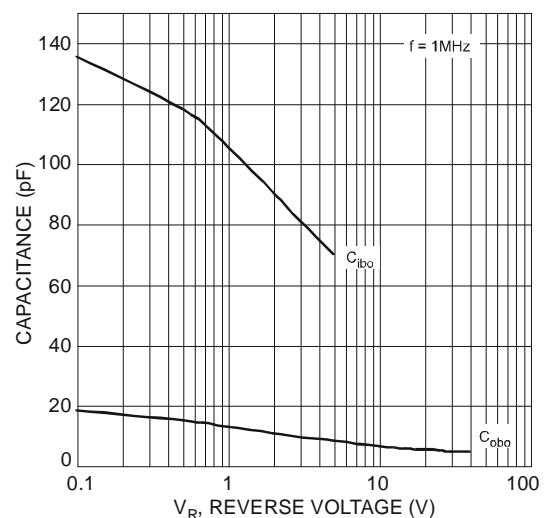
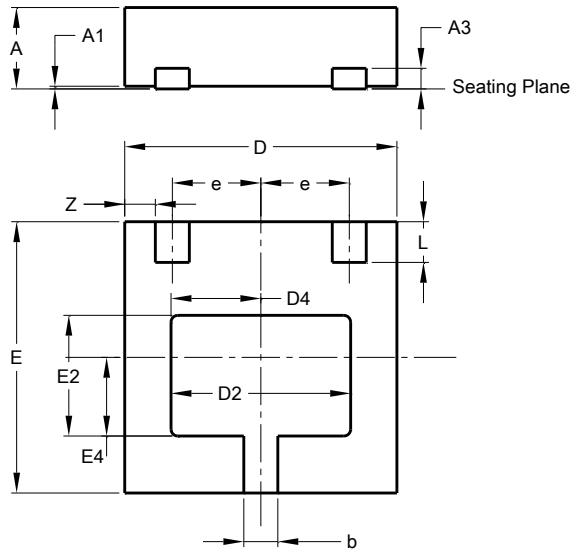


Fig. 6 Typical Capacitance Characteristics

Package Outline Dimensions

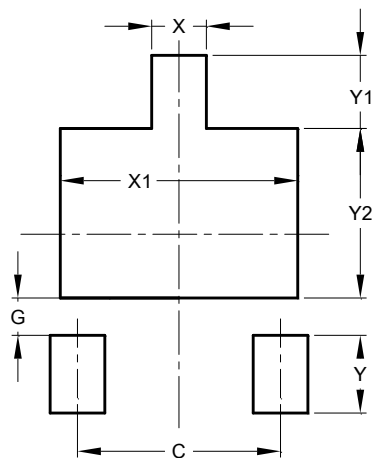
Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



| U-DFN2020-3 (Type B) | | | |
|-------------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.57 | 0.63 | 0.60 |
| A1 | 0.00 | 0.05 | 0.02 |
| A3 | — | — | 0.152 |
| b | 0.20 | 0.30 | 0.25 |
| D | 1.950 | 2.075 | 2.00 |
| D2 | 1.22 | 1.42 | 1.32 |
| D4 | 0.56 | 0.76 | 0.66 |
| E | 1.950 | 2.075 | 2.00 |
| E2 | 0.79 | 0.99 | 0.89 |
| E4 | 0.48 | 0.68 | 0.58 |
| e | — | — | 0.65 |
| L | 0.25 | 0.35 | 0.30 |
| Z | — | — | 0.225 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 1.300 |
| G | 0.240 |
| X | 0.350 |
| X1 | 1.520 |
| X2 | 1.700 |
| Y | 0.500 |
| Y1 | 0.470 |
| Y2 | 1.090 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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